

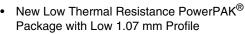


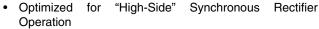
N-Channel 30-V (D-S) MOSFET

PRODUCT SUMMARY					
V _{DS} (V)	$R_{DS(on)}\left(\Omega\right)$	I _D (A)			
30	0.012 at V _{GS} = 10 V	15.7			
	0.020 at V _{GS} = 4.5 V	12.1			

FEATURES

- · Halogen-free available
- TrenchFET[®] Power MOSFET

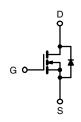




100 % R_g Tested



DC/DC Converters



N-Channel MOSFET

PowerPAK SO-8
6.15 mm
1
50
Bottom View

Ordering Information: Si7888DP-T1-E3 (Lead (Pb)-free)

Si7888DP-T1-GE3 (Lead (Pb)-free and Halogen-free)

Parameter	Symbol	10 s	Steady State	Unit	
Drain-Source Voltage	V_{DS}	30		V	
Gate-Source Voltage	V_{GS}	± 20		V	
Continuous Drain Current (T _{.I} = 150 °C) ^a	T _A = 25 °C		15.7	9.4	
Continuous Diain Current (1) = 150 °C)	T _A = 70 °C		12.5	7.5	
Pulsed Drain Current	I _{DM}	± 50		Α	
Continuous Source Current (Diode Conduction) ^a	I _S	4.1	1.5		
Avalanche Current L = 0.1 mH		I _{AS}	20		
Single Pulse Avalanche Energy	gy L = 0.1 mH		20		mJ
Mariana Damar Disainational	T _A = 25 °C	P _D	5.0	1.8	W
Maximum Power Dissipation ^a	T _A = 70 °C	טי	3.2	1.1	
Operating Junction and Storage Temperature Range	T _J , T _{stg}	- 55 to 150		°C	
Soldering Recommendations (Peak Temperature)b			260	C	

THERMAL RESISTANCE RATINGS						
Parameter	Symbol	Typical	Maximum	Unit		
Marrian In action to Ambient (MOCFET)	t ≤ 10 s	R _{thJA}	21	25	°C/W	
Maximum Junction-to-Ambient (MOSFET) ^a	Steady State	' 'thJA	55	70		
Maximum Junction-to-Case (Drain)	Steady State	R _{thJC}	2.4	3.0		

Notes:

- a. Surface Mounted on 1" x 1" FR4 board.
- b. See Solder Profile (http://www.vishay.com/ppg?73257). The PowerPAK SO-8 is a leadless package. The end of the lead terminal is exposed copper (not plated) as a result of the singulation process in manufacturing. A solder fillet at the exposed copper tip cannot be guaranteed and is not required to ensure adequate bottom side solder interconnection.
- c. Rework Conditions: manual soldering with a soldering iron is not recommended for leadless components.

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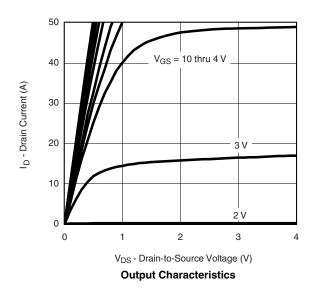
Parameter	Symbol	Test Conditions	Min.	Тур.	Max.	Unit	
Static			l .				
Gate Threshold Voltage	V _{GS(th)}	$V_{DS} = V_{GS}, I_{D} = 250 \mu A$	0.80		2	V	
Gate-Body Leakage	I _{GSS}	$V_{DS} = 0 \text{ V}, V_{GS} = \pm 20 \text{ V}$			± 100	nA	
Zava Cata Valtaga Dvain Cuvvant	1	V _{DS} = 30 V, V _{GS} = 0 V			1		
Zero Gate Voltage Drain Current	I _{DSS}	$V_{DS} = 30 \text{ V}, V_{GS} = 0 \text{ V}, T_{J} = 70 ^{\circ}\text{C}$			5	μΑ	
On-State Drain Current ^a	I _{D(on)}	$V_{DS} \ge 5 \text{ V}, V_{GS} = 10 \text{ V}$	50			Α	
	Ь	$V_{GS} = 10 \text{ V}, I_D = 12.4 \text{ A}$		0.010	0.012		
Drain-Source On-State Resistance ^a	R _{DS(on)}	V _{GS} = 4.5 V, I _D = 9.6 A 0.016		0.016	0.020	Ω	
Forward Transconductance ^a	9 _{fs}	V _{DS} = 15 V, I _D = 12.4 A		27		S	
Diode Forward Voltage ^a	V_{SD}	$I_S = 2.6 \text{ A}, V_{GS} = 0 \text{ V}$		0.75	1.2	V	
Dynamic ^b							
Total Gate Charge	Qg			8.7	10.5		
Gate-Source Charge	Q_{gs}	$V_{DS} = 15 \text{ V}, V_{GS} = 5.0 \text{ V}, I_D = 12.4 \text{ A}$		2.4		nC	
Gate-Drain Charge	Q_{gd}			3.5			
Gate Resistance	R_{g}		0.2	1	1.5	Ω	
Turn-On Delay Time	t _{d(on)}			10	20		
Rise Time	t _r	V_{DD} = 15 V, R_L = 15 Ω		11	20		
Turn-Off Delay Time	t _{d(off)}	$I_D\cong$ 1 A, V_{GEN} = 10 V, R_G = 6 Ω		24	50	ns	
Fall Time	t _f			10	20		
Source-Drain Reverse Recovery Time	t _{rr}	I _F = 2.6 A, di/dt = 100 A/μs		50	75		

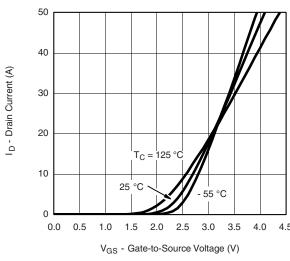
Notes:

- a. Pulse test; pulse width \leq 300 μ s, duty cycle \leq 2 %.
- b. Guaranteed by design, not subject to production testing.

Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

TYPICAL CHARACTERISTICS 25 °C, unless otherwise noted





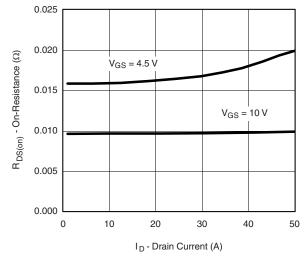
Transfer Characteristics



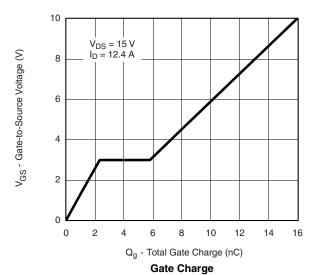


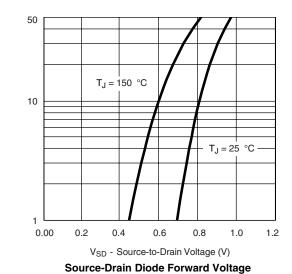


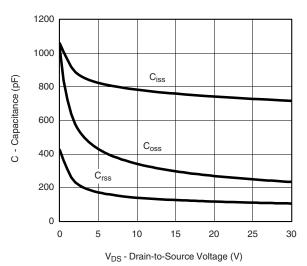
TYPICAL CHARACTERISTICS 25 °C, unless otherwise noted

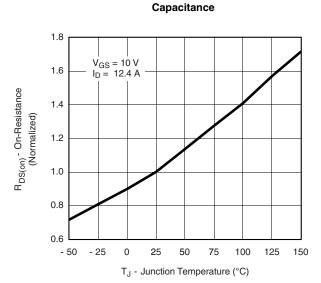


On-Resistance vs. Drain Current

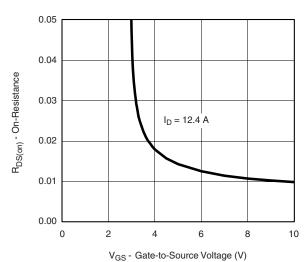








On-Resistance vs. Junction Temperature



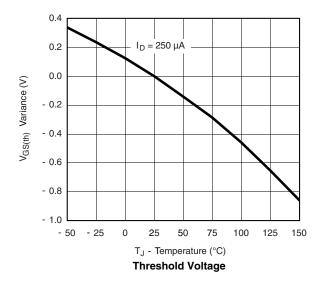
On-Resistance vs. Gate-to-Source Voltage

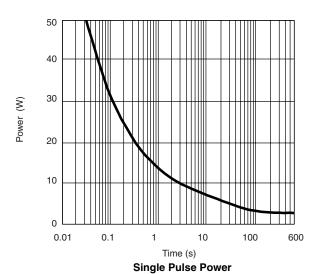
Is - Source Current (A)

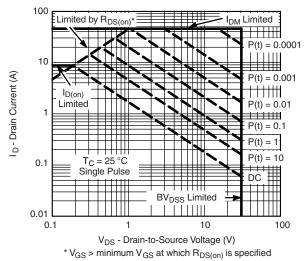
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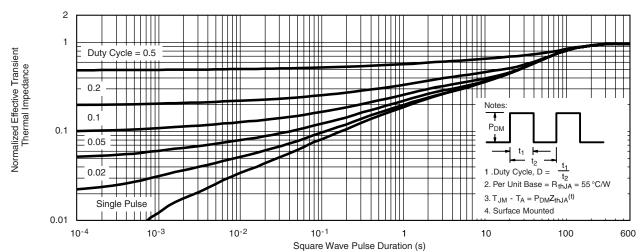
TYPICAL CHARACTERISTICS 25 °C, unless otherwise noted







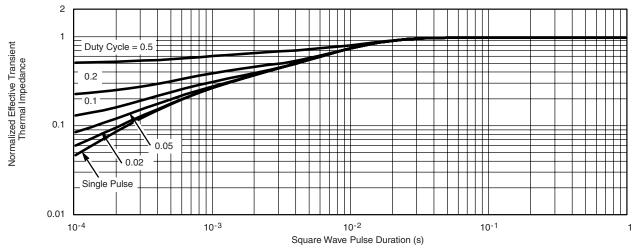
Safe Operating Area



Normalized Thermal Transient Impedance, Junction-to-Ambient



TYPICAL CHARACTERISTICS 25 °C, unless otherwise noted



Normalized Thermal Transient Impedance, Junction-to-Case

Vishay Siliconix maintains worldwide manufacturing capability. Products may be manufactured at one of several qualified locations. Reliability data for Silicon Technology and Package Reliability represent a composite of all qualified locations. For related documents such as package/tape drawings, part marking, and reliability data, see http://www.vishay.com/ppg?71876.

Document Number: 71876 S-80440-Rev. D, 03-Mar-08



DWG: 5881

PowerPAK® SO-8, (Single/Dual)



	3. Dimensions exclusive	of mold flash and cuttin	g burrs.				
DIM.		MILLIMETERS		INCHES			
	MIN.	NOM.	MAX.	MIN.	NOM.	MAX.	
A	0.97	1.04	1.12	0.038	0.041	0.044	
A1		-	0.05	0	-	0.002	
b	0.33	0.41	0.51	0.013	0.016	0.020	
С	0.23	0.28	0.33	0.009	0.011	0.013	
D	5.05	5.15	5.26	0.199	0.203	0.207	
	4.00	4.00	F 00	0.400	0.400	0.407	

Α	0.97	1.04	1.12	0.038	0.041	0.044		
A1		-	0.05	0	-	0.002		
b	0.33	0.41	0.51	0.013	0.016	0.020		
С	0.23	0.28	0.33	0.009	0.011	0.013		
D	5.05	5.15	5.26	0.199	0.203	0.207		
D1	4.80	4.90	5.00	0.189	0.193	0.197		
D2	3.56	3.76	3.91	0.140	0.148	0.154		
D3	1.32	1.50	1.68	0.052	0.059	0.066		
D4		0.57 typ.			0.0225 typ.			
D5		3.98 typ.			0.157 typ.			
E	6.05	6.15	6.25	0.238	0.242	0.246		
E1	5.79	5.89	5.99	0.228	0.232	0.236		
E2 (for AL product)	3.30	3.48	3.66	0.130	0.137	0.144		
E2 (for other product)	3.48	3.66	3.84	0.137	0.144	0.151		
E3	3.68	3.78	3.91	0.145	0.149	0.154		
E4 (for AL product)	0.58 typ.				0.023 typ.			
E4 (for other product)		0.75 typ.		0.030 typ.				
е		1.27 BSC		0.050 BSC				
K (for AL product)		1.45 typ.		0.057 typ.				
K (for other product)		1.27 typ.		0.050 typ.				
K1	0.56	-	=	0.022	-	=		
Н	0.51	0.61	0.71	0.020	0.024	0.028		
L	0.51	0.61	0.71	0.020	0.024	0.028		
L1	0.06	0.13	0.20	0.002	0.005	0.008		
θ	0°	-	12°	0°	-	12°		
W	0.15	0.25	0.36	0.006	0.010	0.014		
M	0.125 typ.			0.005 typ.				
ECN: C13-0702-Rev. K, 20)-May-13			•				

Revison: 20-May-13 Document Number: 71655



RECOMMENDED MINIMUM PADS FOR PowerPAK® SO-8 Single



Recommended Minimum Pads Dimensions in Inches/(mm)

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APPLICATION NOTE



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Revision: 02-Oct-12 Document Number: 91000